# **Amplifier Transistor**

## **PNP Silicon**

### **Features**

• Pb-Free Packages are Available\*

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CE</sub>	-25	Vdc
Collector - Base Voltage	V <sub>CB</sub>	-25	Vdc
Emitter - Base Voltage	V <sub>EB</sub>	-4.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	-200	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

## THERMAL CHARACTERISTICS

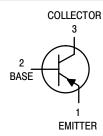
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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## MARKING DIAGRAM





MPS4126 = Device Code A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPS4126RLRA	TO-92	2,000/Tape & Reel
MPS4126RLRAG	TO-92 (Pb-Free)	2,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **MPS4126**

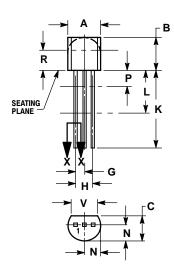
# ELECTRICAL OHARACTERISTICS (TA = 25°C unless otherwise noted)

<u> </u>	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·			
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mA}, I_B = 0)$	V <sub>(BR)CEO</sub>	-25	_	Vdc
Collector – Base Breakdown Voltage ( $I_C = -10 \mu A, I_E = 0$ )	V <sub>(BR)CBO</sub>	-25	-	Vdc
Emitter – Base Breakdown Voltage $(I_C = 0, I_E = -10 \mu A)$	V <sub>(BR)EBO</sub>	-4.0	_	Vdc
Collector Cutoff Current $(V_{CB} = -20 \text{ V}, I_E = 0)$	I <sub>CBO</sub>	_	-50	nAdc
Emitter Cutoff Current $(V_{EB} = -3.0 \text{ V}, I_C = 0)$	I <sub>EBO</sub>	-	-50	nAdc
ON CHARACTERISTICS	<u>.</u>			
DC Current Gain $(I_C = -2.0 \text{ mA}, V_{CE} = -1.0 \text{ V})$ $(I_C = -50 \text{ mA}, V_{CE} = -1.0 \text{ V})$	h <sub>FE</sub>	120 60	360 -	-
Collector – Emitter Saturation Voltage $(I_C = -50 \text{ mA}, I_B = -5.0 \text{ mA})$	V <sub>CE(sat)</sub>	-	-0.4	Vdc
Base – Emitter Saturation Voltage (I <sub>C</sub> = –50 mA, I <sub>B</sub> = –5.0 mA)	V <sub>BE(sat)</sub>	_	-0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	•		•	
Current – Gain — Bandwidth Product $(I_C = -10 \text{ mA}, V_{CE} = -20 \text{ V}, f = 100 \text{ MHz})$	f <sub>T</sub>	170	_	MHz
Output Capacitance $(V_{CB} = -5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>ob</sub>	-	4.5	pF
Input Capacitance $(V_{EB} = -0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz})$	C <sub>ib</sub>	_	11.5	pF
Small-Signal Current Gain (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = 1.0 V, f = 1.0 kHz)	h <sub>fe</sub>	120	480	-
Noise Figure (I <sub>C</sub> = $-100  \mu \text{A}$ , V <sub>CE</sub> = $-5.0  \text{V}$ , R <sub>S</sub> = $1.0  \text{k}\Omega$ , f = $1.0  \text{kHz}$ )	NF	-	4.0	dB

## 查询"MPS4126RLRAG"供应商

## PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 114-3M, 1902.
  CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R
  IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P AND
- BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

STYLE 1:

PIN 1. EMITTER

BASE 2.

COLLECTOR

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